

ORDERING INFORMATION					
Temp. Range	Package	Part Number			
		DG411DJ DG411DJ-E3			
	16-pin plastic DIP	DG412DJ DG412DJ-E3			
		DG413DJ DG413DJ-E3			
- 40 °C to 85 °C	16-pin narrow SOIC	DG411DY DG411DY-E3 DG411DY-T1 DG411DY-T1-E3			
		DG412DY DG412DY-E3 DG412DY-T1 DG412DY-T1-E3			
		DG413DY DG413DY-E3 DG413DY-T1 DG413DY-T1-E3			
		DG411DQ-E3 DG411DQ-T1-E3			
		DG412DQ-E3 DG412DQ-T1-E3			
		DG413DQ-E3 DG413DQ-T1-E3			

ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
V + to V -		44				
GND to V -		25				
V <sub>L</sub>		(GND - 0.3) to (V+) + 0.3	V			
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) -2 to (V+) + 2 or 30 mA, whichever occurs first				
Continuous Current (Any terminal)		30	mA			
Peak Current, S or D (Pulsed at 1 m	s, 10 % duty cycle)	100	] ""^			
Storage Temperature	(AK, AZ suffix)	- 65 to 150	°C			
Storage remperature	(DJ, DY suffix)	- 65 to 125	O			
	16-pin plastic DIP <sup>c</sup>	470				
Power Dissipation (Package) <sup>b</sup>	16-pin narrow SOIC <sup>d</sup>	600	mW			
	16-pin CerDIP <sup>e</sup>	900	11100			
	LCC-20 <sup>e</sup>	900				

#### Notes:

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V + or V will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 25 °C.
- d. Derate 7.6 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.



SPECIFICATIONS	S <sup>a</sup>								
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		
Parameter	Symbol	V + = 15 V, V - = -15 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$	Temp.b	Typ.c	Min.d	Max. <sup>d</sup>	Min.d	Max.d	Unit
Analog Switch	-	2 111	•	, , , , , , , , , , , , , , , , , , ,		I	I	I	
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V + = 13.5  V, V - = -13.5  V $I_S = -10 \text{ mA}, V_D = \pm 8.5 \text{ V}$	Room Full	25		35 45		35 45	Ω
Switch Off Leakage	I <sub>S(off)</sub>	V + = 16.5, V - = - 16.5 V	Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	
Current	I <sub>D(off)</sub>	$V_D = \pm 15.5 \text{ V}, V_S = \pm 15.5 \text{ V}$	Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	nA
Channel On Leakage Current	I <sub>D(on)</sub>	V + = 16.5  V, V - = -16.5  V $V_S = V_D = \pm 15.5 \text{ V}$	Room Full	± 0.1	- 0.4 - 40	0.4 40	- 0.4 - 10	0.4 10	
Digital Control									
Input Current, V <sub>IN</sub> Low	$I_{IL}$	V <sub>IN</sub> under test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μΑ
Input Current, V <sub>IN</sub> High	I <sub>IH</sub>	$V_{IN}$ under test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μπ
Dynamic Characteristics	S								
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Room Full	110		175 240		175 220	
Turn-Off Time	t <sub>OFF</sub>	$V_S = \pm 10 \text{ V}$ , see figure 2	Room Full	100		145 160		145 160	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG413 only, $V_S = 10 \text{ V}$ $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room	25					
Charge Injection	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega$ $C_L = 10 \text{ nF}$	Room	5					рC
Off Isolation <sup>e</sup>	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF,$	Room	68					
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	f = 1 MHz	Room	85					dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>		Room	9					
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room	9					pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>	1 – 1 WH 12	Room	35					Pi
Power Supplies						•	•		
Positive Supply Current	l+		Room Full	0.0001		1 5		1 5	
Negative Supply Current	l-	V + = 16.5 V, V - = - 16.5 V	Room Full	- 0.0001	- 1 - 5		- 1 - 5		μΑ
Logic Supply Current	ΙL	$V_{IN} = 0 V \text{ or } 5 V$	Room Full	0.0001		1 5		1 5	μΛ
Ground Current	I <sub>GND</sub>		Room Full	- 0.0001	- 1 - 5		- 1 - 5		



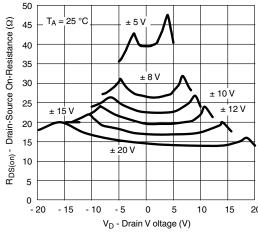
SPECIFICATIONS <sup>a</sup> (for Unipolar Supplies)									
Parameter	Symbol	Test Conditions Unless Specified	Temp.b	Typ. <sup>c</sup>	<b>A Suffix</b> - 55 °C to 125 °C		<b>D Suffix</b> - 40 °C to 85 °C		Unit
rarameter	Cymbol	V += 12 V, V -= 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$	Temp.		Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Oint
Analog Switch									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full			12		12	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V += 10.8  V, $I_S = -10 \text{ mA}, V_D = 3 \text{ V}, 8 \text{ V}$	Room Full	40		80 100		80 100	Ω
Dynamic Characteristics	Dynamic Characteristics								
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Room Hot	175		250 400		250 315	
Turn-Off Time	t <sub>OFF</sub>	$V_S = 8 V$ , see figure 2	Room Hot	95		125 140		125 140	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG413 only, $V_S = 8 V$ $R_L = 300 Ω$ , $C_L = 35 pF$	Room	25					
Charge Injection	Q	$V_g = 6 \text{ V}, R_g = 0 \Omega, C_L = 10 \text{ nF}$	Room	25					рС
Power Supplies									
Positive Supply Current	l+		Room Hot	0.0001		1 5		1 5	
Negative Supply Current	I-	V - 12 5 V V - 0 V or 5 V	Room Hot	- 0.0001	- 1 - 5		- 1 - 5		
Logic Supply Current	ΙL	$V + = 13.5 \text{ V}, V_{IN} = 0 \text{ V or } 5 \text{ V}$	Room Hot	0.0001		1 5		1 5	μΑ
Ground Current	I <sub>GND</sub>		Room Hot	- 0.0001	- 1 - 5		- 5		

#### Notes:

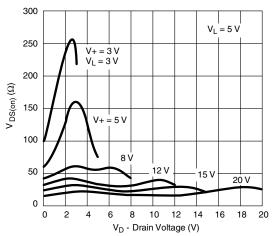
- a. Refer to process option flowchart.
- b.Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e.Guaranteed by design, not subject to production test.
- f. V<sub>IN</sub> = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



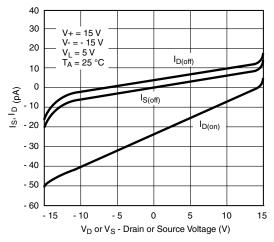
On-Resistance vs. V<sub>D</sub> and Power Supply Voltage



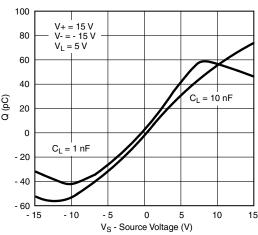
On-Resistance vs. V<sub>D</sub> and Unipolar Supply Voltage



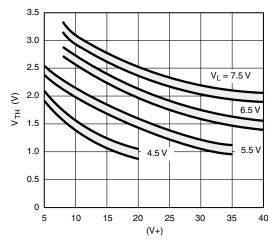
#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



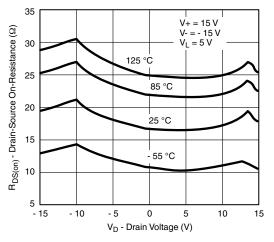
Leakage Current vs. Analog Voltage



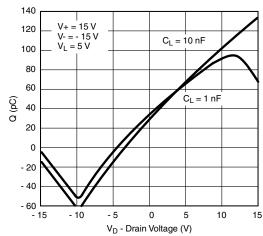
Charge Injection vs. Analog Voltage



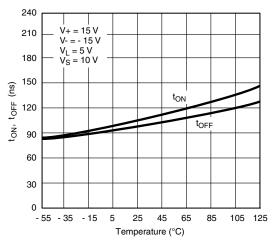
Input Switching Threshold vs. Supply Voltage



I<sub>D</sub>, I<sub>S</sub> Leakages vs. Temperature



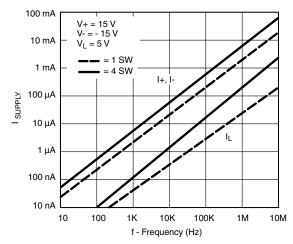
Charge Injection vs. Analog Voltage



Switching Time vs. Temperature

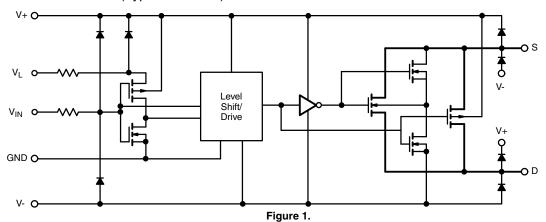
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Supply Current vs. Input Switching Frequency

### **SCHEMATIC DIAGRAM** (Typical Channel)



#### **TEST CIRCUITS**

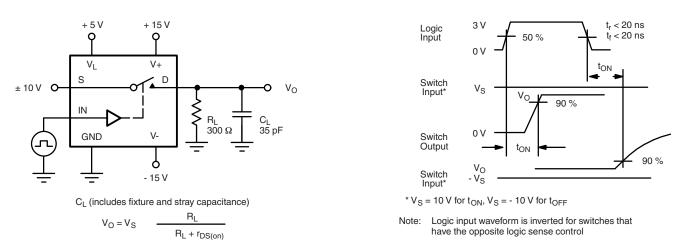
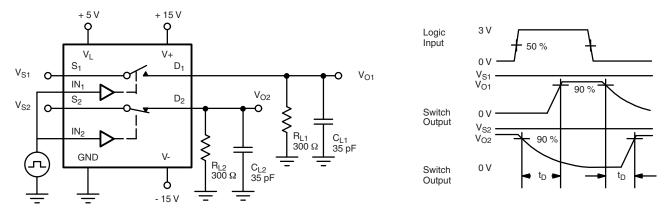


Figure 2. Switching Time



#### **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

Figure 3. Break-Before-Make (DG413)

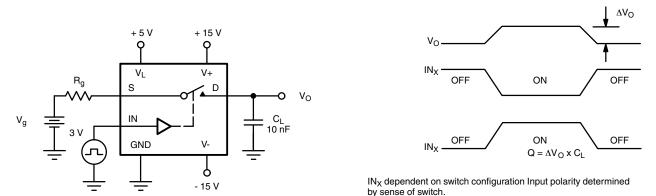


Figure 4. Charge Injection

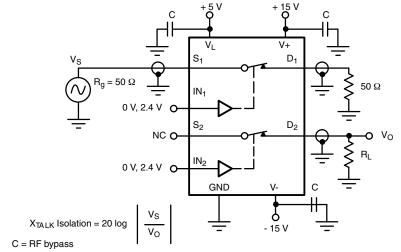


Figure 5. Crosstalk



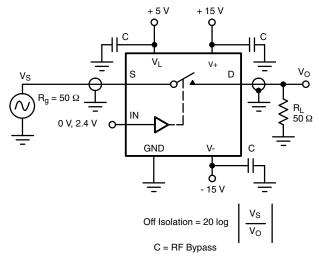


Figure 6. Off Isolation

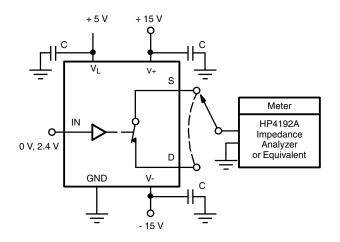


Figure 7. Source/Drain Capacitances

#### **APPLICATIONS**

#### **Single Supply Operation:**

The DG411, DG412, DG413 can be operated with unipolar supplies from 5 V to 44 V. These devices are characterized and tested for unipolar supply operation at 12 V to facilitate the majority of applications. In single supply operation, V+ is tied to V $_{\rm L}$  and V- is tied to 0 V. See Input Switching Threshold vs. Supply Voltage curve for V $_{\rm L}$  versus input threshold requirments.

#### **Summing Amplifier**

When driving a high impedance, high capacitance load such as shown in figure 8, where the inputs to the summing amplifier have some noise filtering, it is necessary to have shunt switches for rapid discharge of the filter capacitor, thus preventing offsets from occurring at the output.

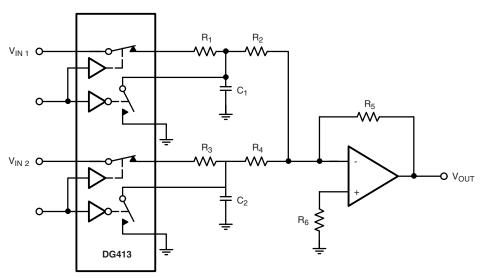
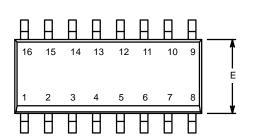


Figure 8. Summing Amplifier

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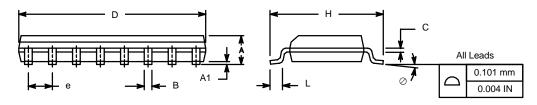
SOIC (NARROW): 16-LEAD
JEDEC Part Number: MS-012



	MILLIMETERS		INC	HES			
Dim	Min	Max	Min	Max			
Α	1.35	1.75	0.053	0.069			
A <sub>1</sub>	0.10	0.20	0.004	0.008			
В	0.38	0.51	0.015	0.020			
С	0.18	0.23	0.007	0.009			
D	9.80	10.00	0.385	0.393			
E	3.80	4.00	0.149	0.157			
е	1.27	BSC	0.050	BSC			
Н	5.80	6.20	0.228	0.244			
L	0.50	0.93	0.020	0.037			
0	0°	8°	0°	8°			
FCN: S-0	FCN: S-03946—Rev F 09-Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

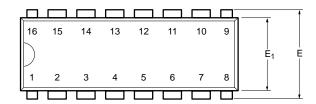
DWG: 5300

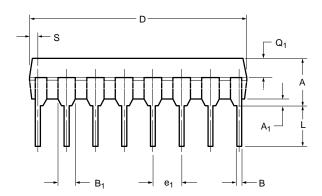


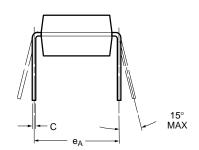
Document Number: 71194 www.vishay.com 02-Jul-01 sww.vishay.com



PDIP: 16-LEAD





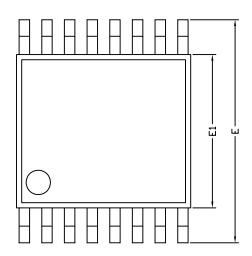


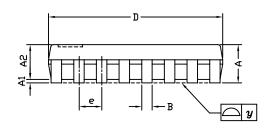
	MILLIM	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A <sub>1</sub>	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B <sub>1</sub>	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	18.93	21.33	0.745	0.840	
Е	7.62	8.26	0.300	0.325	
E <sub>1</sub>	5.59	7.11	0.220	0.280	
e <sub>1</sub>	2.29	2.79	0.090	0.110	
e <sub>A</sub>	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
$Q_1$	1.27	2.03	0.050	0.080	
S	0.38	1.52	.015	0.060	
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

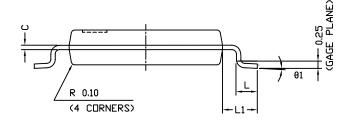
Document Number: 71261 www.vishay.com 06-Jul-01 sum.vishay.com



**TSSOP: 16-LEAD** 







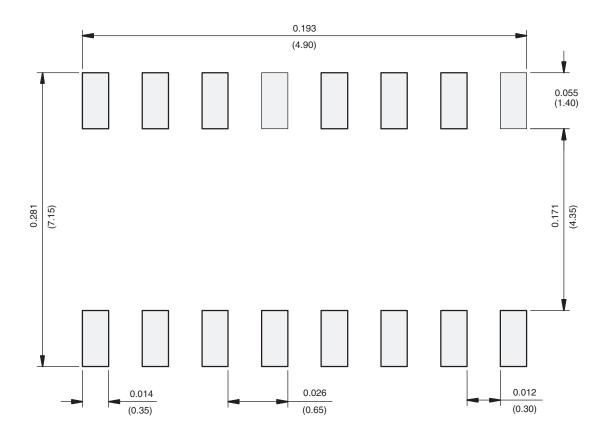
	DIMENSIONS IN MILLIMETERS					
Symbols	Min	Nom	Max			
Α	-	1.10	1.20			
A1	0.05	0.10	0.15			
A2	=	1.00	1.05			
В	0.22	0.28	0.38			
С	=	0.127	-			
D	4.90	5.00	5.10			
E	6.10	6.40	6.70			
E1	4.30	4.40	4.50			
е	-	0.65	-			
L	0.50	0.60	0.70			
L1	0.90	1.00	1.10			
у	=	-	0.10			
θ1	0°	3°	6°			
ECN: S-61920-Rev. D. 23-0	Oct-06					

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



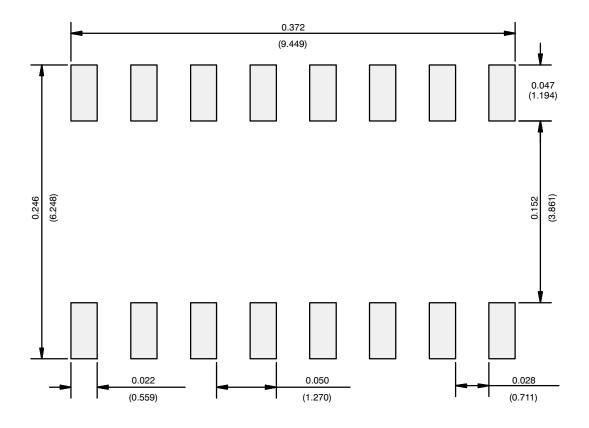
#### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



#### **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE

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